# UAF1780-1781-1782

## DUAL 2 A LOW DROP OUT INTELLIGENT POWER SWITCH

ADVANCE DATA

- LOW POWER DISSIPATION (LOW V<sub>SAT</sub>: 0.6 V @ 2 A)
- ALL INPUTS ARE OPERATIONAL WITH CONTROL SIGNALS HIGHER THAN V<sub>CC</sub>
- ALL INPUTS WITHSTAND VOLTAGES LOWER THAN GROUND
- HIGH OUTPUT CURRENTS
- PROTECTION OF OUTPUT TRANSISTORS (UP TO + 32 V)
- THE OUTPUTS CAN WITHSTAND VOLTAGES LOWER THAN GROUND
- WITHSTAND ON Vcc SPIKES UP TO (60 V, 10 ms)
- DIFFERENTIAL INPUTS

#### DESCRIPTION

The UAF1780-1781-1782 are dual interface circuits delivering high output currents and capable of driving any type of load.

An on-chip dc/dc conversion unit in conjuction with a few low-cost external components (a low value inductor and a low voltage capacitor) are implemented to limit the saturation voltage thereby optimizing the efficiency.

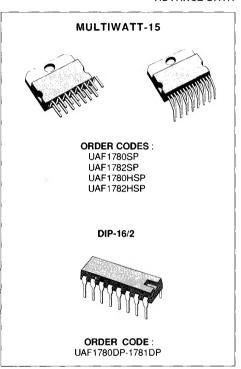
The devices are particularly well protected against destructive overloads. Each output implements a current limit circuitry, a desaturation monitoring unit for the detection of overloads and short-circuits, and a thermal protection feature.

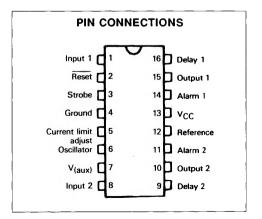
Corresponding output is turned off in case of prolonged desaturation or excessive internal dissipation. This condition is reflected by a low level on ALARM output terminal. This protection unit can be reactivated by applying a logic low signal to RESET input.

However, for inductive loads, a delay is imposed on signal applied to this RESET input so as to prevent a rapid and premature conduction of output transistors.

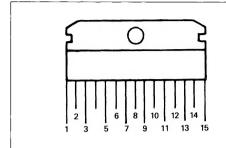
A logic high signal applied to STROBE input will disable both power outputs.

The devices operates within a supply voltage range of + 8 V to + 32 V.





#### **PIN CONNECTIONS**



1 -Oscillator	9-V <sub>CC</sub>
2 -V <sub>(aux)</sub>	10-Output
3-Input 2	11 - Alarm 1
4 -Delay 2	12-Delay 1
5-Alarm 2	13-Input 1
6 -Reference	14-Reset
7 -Output 2	15-Strobe

1

8-Ground

#### **ABSOLUTE MAXIMUM RATINGS**

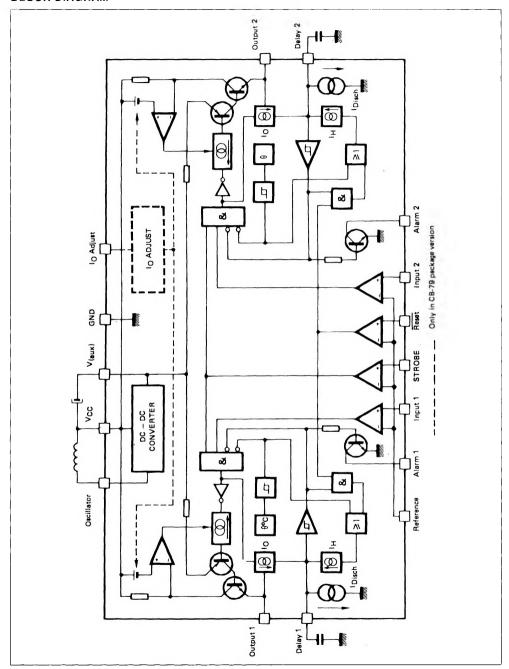
Symbol	Parameter	Value	Unit	
V <sub>CC</sub> (*)	Supply Voltage	+ 35	V	
V <sub>I1</sub> V <sub>I2</sub> V <sub>reset</sub> V <sub>strobe</sub>	Input Voltages	30 to + 55	V	
I <sub>0</sub>	Output Current	Internally Limited	Α	
ΙL	Current In DC/DC Converter Inductance	0.4	Α	
Ptot	Total Power Dissipation	Internally Limited	W	
Toper	Operating Free-air Temperature Range	- 40 to + 85	°C	
Tj	Junction Temperature	+ 150	°C	

<sup>+ 60</sup> V (10 mS)

#### THERMAL DATA

R <sub>th(j-c)</sub>	Maximum Junction-case Thermal Resistance	DIP.16	25	°C/W
		Multiwatt	2.5	
R <sub>th(j-a)</sub>	Maximum Junction-ambient Thermal	DIP.16	70	°C/W
	Resistance	Multiwatt	40	

#### **BLOCK DIAGRAM**



### **ELECTRICAL CHARACTERISTICS**

 $V_{CC}$  = + 24 V, -40 °C,  $\leq$  T<sub>amb</sub>  $\leq$  + 85 °C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
Vcc	Supply Voltage	8		32	V
Icc	Supply Current Input 1 = Input 2 : Low Input 1 = Input 1 : High, I <sub>O</sub> = 2 x 2 A	_	7 25	32	mA
J <sub>1</sub>	Input Current (all inputs) $ \begin{array}{l} V_1 > V_{ret} \\ V_1 < V_{ref} \end{array} $		15 0	50	
I <sub>OHA</sub>	High Level Alarm Output Leakage Current (V <sub>A</sub> = + 10 V)		0	10	μА
VOLA	Low Level Alarm Output Voltage (I <sub>A</sub> = + 10 mA)		1.1	1.3	V
V <sub>CC</sub> - V <sub>O</sub>	Power Outputs Dropout Voltage $I_O = 0.5 \text{ A}$ $I_O = 1 \text{ A}$ $I_O = 2 \text{ A}$		0.15 0.3 0.6	0.25 0.4 0.7	V
loL	Power Outputs Leakage Current			100	μА
treset	Reset Pulse Duration (C1 = C2 = 1 μF)		400		mS
t <sub>d</sub>	Delay Time before Desaturation Monitoring Unit Becomes Active (C1 = C2 = $1\mu$ F) $V_{CC} - V_O = + 12 V$ $V_{CC} - V_O = + 24 V$ $V_{CC} - V_O = + 32 V$		20 10 5		mS
V <sub>ref</sub>	Reference Input Voltage	1.4		55	V
I <sub>ref</sub>	Reference Input Current ( $V_{ret}$ = 1.4 V) All Inputs < $V_{ret}$ All Inputs > $V_{ret}$	- 1	80 0	150 + 1	μА
10	Available Output Current $\begin{array}{ccc} & & & & & & & & & & \\ & & & & & & & & $	2.5 1 2.5 2 1 2			А
V <sub>CC</sub> - V <sub>O</sub>	Maximum Output Voltage Swing		-	50	V
V <sub>aux</sub> - V <sub>CC</sub>	DC/DC Output Voltage 0.5 A < $I_0$ < 2 A (each output) CO = 47 $\mu$ F, L = 100 $\mu$ H		1.25		V

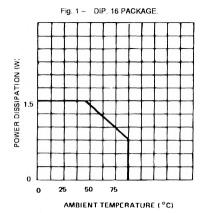


Fig. 3 – AVAILABLE OUTPUT CURRENT VS EXTERNAL RESISTANCE VALUE DIP. 16 PACKAGE.

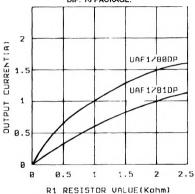


Fig 5 RESPONSE TIME

O 0.4 0.8

TIME (µS)

Fig 2 - MULTIWATT PACKAGE

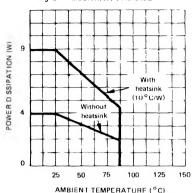


Fig. 4 - SATURATION VOLTAGE VS

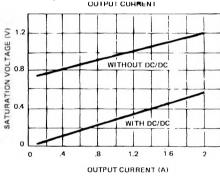


Fig. 6 RESPONSE TIME.

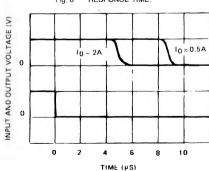
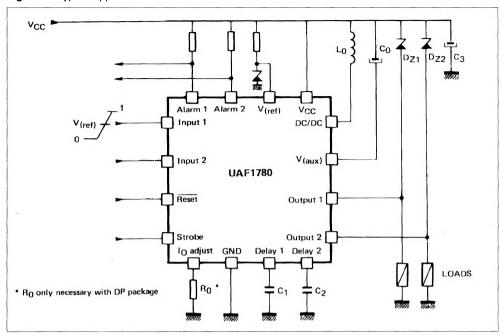


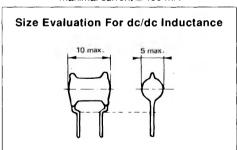
Figure 7: Typical Application.



 L<sub>O</sub> and C<sub>O</sub> are the external elements of the dc/dc converter. Typical values and characteristics of these components are as follows:

For  $L_O$ : - inductance = 100  $\mu$ H (tolerance + 10%)

- maximal current ≥ 400 mA



For  $C_0$ : The value of this capacitor is not critical, a capacitor of  $C1 \ge 47$  F,  $Vn \ge 6.3$  V will be suitable for the majority of the applications.

The on-chip dc/dc converter can be disabled by connecting  $V_{(aux)}$  terminal to  $V_{CC}$  and leaving "Oscillator" pin floating.

- C<sub>1</sub> and C<sub>2</sub> implement two distinct functions :
  - response time required by the desaturation monitoring unit to become active.
  - time delay imposed on each power output prior to conduction.

$$t_d = \frac{C \cdot 3.5 \text{ V}}{7 \,\mu\text{A}}$$

With  $C_2 = C_3 = 1 \mu F$ , the outputs are protected against voltage transients of as high as + 32 V and the response time of the desaturation monitoring unit is 400 ms.

- Dz1 and Dz2 Zener Diodes are required in the case of inductive loads. Vz of these diodes should be < 60 V.</li>
- R<sub>0</sub> determines the value of maximum output current (DIP package). Its value is given in curve 3, where output current values are plotted against the corresponding values of this resistor.